

ST40200C STB40200C

Technical Data Data Sheet N1440, Rev. B

RoHS

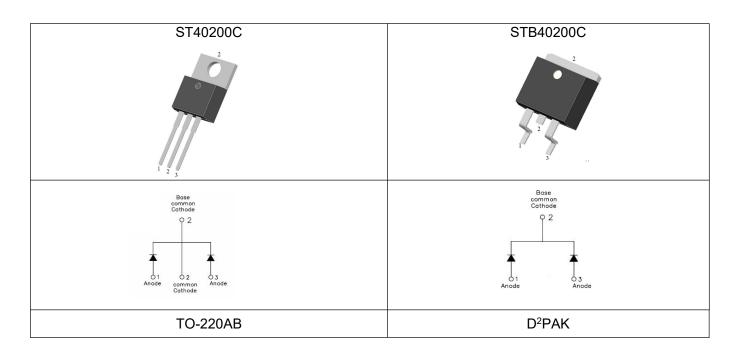
ST40200C/STB40200C SCHOTTKY RECTIFIER

Applications

- Switching power supply
- Converters
- **Free-Wheeling diodes**
- **Reverse battery protection**

Features

- 150 °C T_J operation
- Ultralow forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Trench MOS Schottky technology Terminals finish: 100% Pure Tin
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



Maximum Ratings(limiting values, at 25 °C unless otherwise specified)

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	200	V
Average Rectified Forward Current	I _{F (AV)}	Tc=93°C, In DC	20(Per Leg) 40(Per Device)	А
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I _{FSM}	8.3ms, Half Sine pulse	250	А

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Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	V _{F1}	@ 20A, Pulse, T _J = 25 °C	0.83	1.60	V
	V _{F2}	@ 20A, Pulse, T _J = 125 °C	0.71	0.76	V
Reverse Current(Per Leg)*	I _{R1}	@V _R = rated V _R T _J = 25 °C	0.03	300	uA
	I _{R2}	@V _R = rated V _R T _J = 125 °C	0.08	36	mA
Junction Capacitance (per leg)	Ст	@V _R = 5V, T _C = 25 °C f _{SIG} = 1MHz	336	-	pF

* Pulse width < 300 µs, duty cycle < 2%

Thermal-Mechanical Specifications:

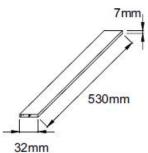
Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case(Per Leg)	$R_{ ext{ heta}JC}$	DC operation	1.8	°C/W

Tube Specification

Device	Package	Weight	Shipping
ST40200C	TO-220AB	2.0	50pcs / tube
STB40200C	D ² PAK	1.85	800pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Tube Specification(TO-220AB)





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Ratings and Characteristics Curves

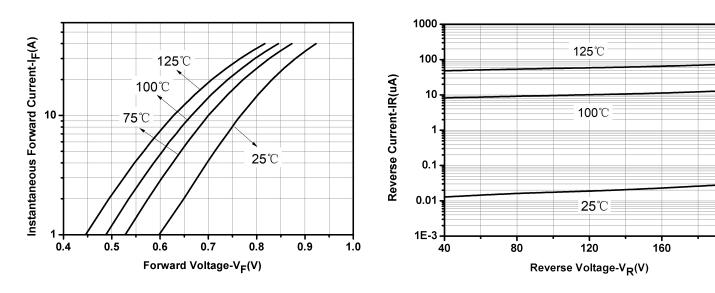
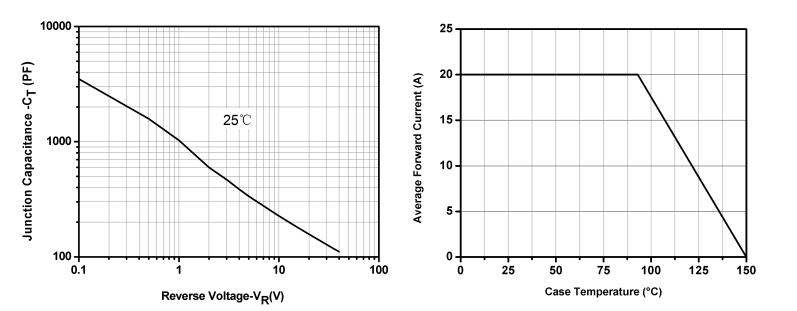


Fig.1-Typical Forward Voltage Characteristics





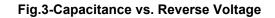


Fig.4- Forward Current Derating Curve

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Marking Diagram



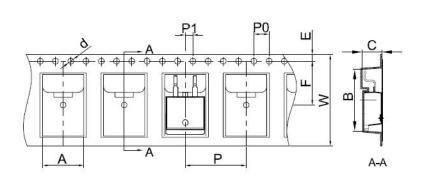
STB4	102000
SSG	XXXXX
	0
H	ЧΗ
Н	Н

Where XXXXX is YYWWL

ST	= Device Type
B	= Package type
40	= Forward Current (40A)
200	= Reverse Voltage (200V)
C	= Configuration
SSG	= SSG
YY	= Year
YY	= Year
WW	= Week
L	= Lot Number
_	Molding resin

Epoxy resin UL:94V-0

Carrier Tape Specification D2PAK



SYMBOL	Millimeters		
	Min.	Max.	
А	10.70	10.90	
В	16.03	16.23	
С	5.11	5.31	
d	1.45	1.65	
E	1.65	1.85	
F	11.40	11.60	
P0	3.90	4.10	
Р	15.90	16.10	
P1	1.90	2.10	
W	23.90	24.30	



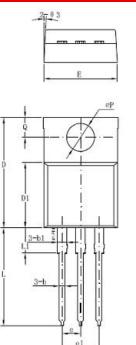


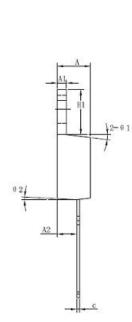


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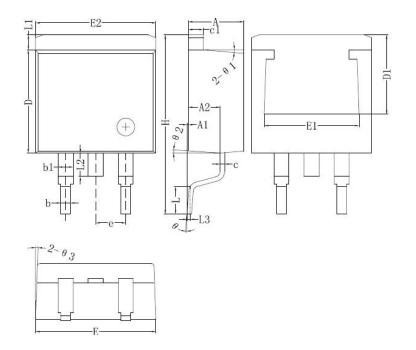
Mechanical Dimensions TO-220AB





Symbol	Dimensions in millimeters		
	Min	Typical	Max
A	3.56	-	4.83
A1	0.51	-	1.40
A2	2.03	-	2.92
b	0.38	-	1.02
b1	1.14	-	1.78
С	0.31	-	0.61
D	14.22	-	16.51
D1	8.38	-	9.42
E	9.65	-	10.67
е	-	2.54	-
e1	-	5.08	-
H1	5.84	-	6.86
L	12.70	-	14.73
L1	-	-	6.35
ΦΡ	-	3.56	-
Q	2.54	-	3.43

Mechanical Dimensions D²PAK



Symbol	Dimensions in millimeters		
eyniser	Min.	Max.	
А	4.06	4.83	
A1	0	0.26	
b	0.51	0.99	
b1	1.14	1.78	
С	0.31	0.74	
c1	1.14	1.65	
D	8.38	8.65	
D1	6.86		
E1	6.22		
E2	9.65	10.67	
е	2.54BSC		
Н	14.60	15.88	
L	1.78	2.80	
L1	-	1.68	
L2	- 1.78		
L3	0.255BSC		
Θ	0	8°	

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